Contents

Related Documentation

The MPXM2051G device features and operations are described in a variety of reference manuals, user guides, and application notes. To find the most-current versions of these documents:

1.   Go to the NXP homepage at:

http://www.nxp.com/

2.   In the Keyword search box at the top of the page, enter the device number MPXM2051G.

3.   In the Refine Your Result pane on the left, click on the Documentation link.

MPXM2051G

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1 General Description

1.1 Block diagram

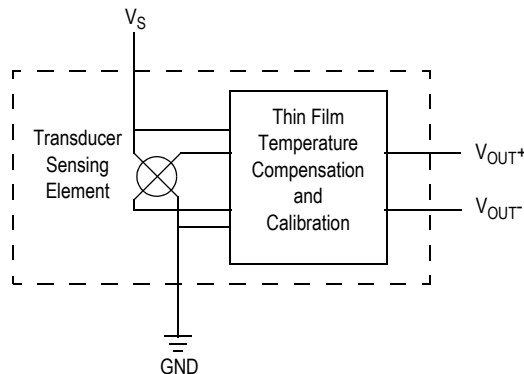Figure 1 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

Figure 1. Integrated pressure sensor block diagram

1.2 Pinout
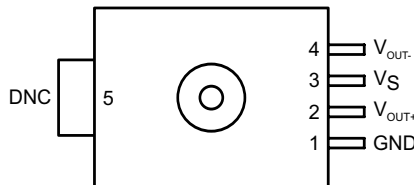
Figure 2. Device pinout (top view)

Table 1. Pin functions

Pin	Name	Function
1	GND	Ground
2	V_{OUT+}	Output voltage
3	V_S	Voltage supply
4	V_{OUT-}	Output voltage
5	DNC	Do not connect to external circuitry or ground.

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2 Mechanical and Electrical Specifications

2.1 Maximum ratings

Table 2. Maximum ratings[1]

Rating	Symbol	Value	Unit
Maximum Pressure	P_{max}	200	kPa
Storage Temperature	T_{stg}	-40 to +125	°C
Operating Temperature	T_A	-40 to +125	°C

1.Exposure beyond the specified limits may cause permanent damage or degradation to the device.

2.2 Operating characteristics

Table 3. Operating characteristics (V_S = 10 Vdc, T_A = 25°C.)

Characteristic	Symbol	Min	Typ	Max	Unit
Pressure Range[1]	P_{OP}	0	—	50	kPa
Supply Voltage[2]	V_S	—	10	16	Vdc
Supply Current	I_o	—	6.0	—	mAdc
Full Scale Span[3]	V_{FSS}	38.5	40	41.5	mV
Offset[4]	V_{off}	-1.0	—	1.0	mV
Sensitivity	$\Delta V/\Delta P$	—	0.8	—	mV/kPa
Linearity[5]	—	-0.3	—	0.3	$\%V_{FSS}$
Pressure Hysteresis[5] (0 to 50 kPa)	—	—	±0.1	—	$\%V_{FSS}$
Temperature Hysteresis[5] (-40 °C to +125 °C)	—	—	±0.5	—	$\%V_{FSS}$
Temperature Effect on Full Scale Span[5]	TCV_{FSS}	-1.0	—	1.0	$\%V_{FSS}$
Temperature Effect on Offset[5]	TCV_{off}	-1.0	—	1.0	mV
Input Impedance	Z_{in}	1000	—	2500	Ω
Output Impedance	Z_{out}	1400	—	3000	Ω
Response Time[6] (10% to 90%)	t_R	—	1.0	—	ms
Warm-Up	—	—	20	—	ms
Offset Stability[7]	—	—	±0.5	—	$\%V_{FSS}$

1.   1.0 kPa (kiloPascal) equals 0.145 psi.

2.   Device is ratiometric within this specified excitation range. Operating the device above the specified excitation range may induce additional error due to device self-heating.

3.   Full Scale Span (V_{FSS}) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.

4.   Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.

5.   Accuracy (error budget) consists of the following:

   • Linearity: Output deviation from a straight line relationship with pressure, using end point method, over the specified pressure range.

   • Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.

   • Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25 °C.

   • TcSpan: Output deviation at full rated pressure over the temperature range of 0°C to 85 °C, relative to 25 °C.

   • TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0 °C to 85 °C, relative to 25 °C.

6.   Response Time is defined as the time for the incremental change in the output to go from 10% to 90% of its final value when subjected to a specified step change in pressure.

7.   Offset stability is the product's output deviation when subjected to 1000 hours of Pulsed Pressure, Temperature Cycling with Bias Test.

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2.3　Voltage output versus applied differential pressure

The differential voltage output of the sensor is directly proportional to the differential pressure applied.

The output voltage of the differential or gauge sensor increases with increasing pressure applied to the pressure side relative to the vacuum side. Similarly, output voltage increases as increasing vacuum is applied to the vacuum side relative to the pressure side.

2.4　Linearity

Linearity refers to how well a transducer's output follows the equation: $V_{OUT} = V_{OFF}$ + sensitivity x P over the operating pressure range. There are two basic methods for calculating nonlinearity: (1) end point straight line fit (see Figure 3) or (2) a least squares best line fit. While a least squares fit gives the "best case" linearity error (lower numerical value), the calculations required are burdensome.

Conversely, an end point fit will give the "worst case" error (often more desirable in error budget calculations) and the calculations are more straightforward for the user. The specified pressure sensor linearities are based on the end point straight line method measured at the midrange pressure.
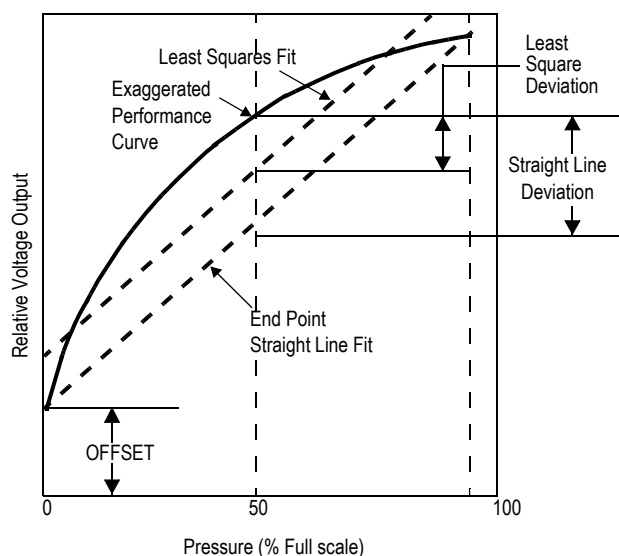

Figure 3. Linearity specification comparison

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3   On-chip Temperature Compensation and Calibration

Figure 4 shows the minimum, maximum and typical output characteristics of the MPXM2051G series at 25 °C. The output is directly proportional to the differential pressure and is essentially a straight line.

A silicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.
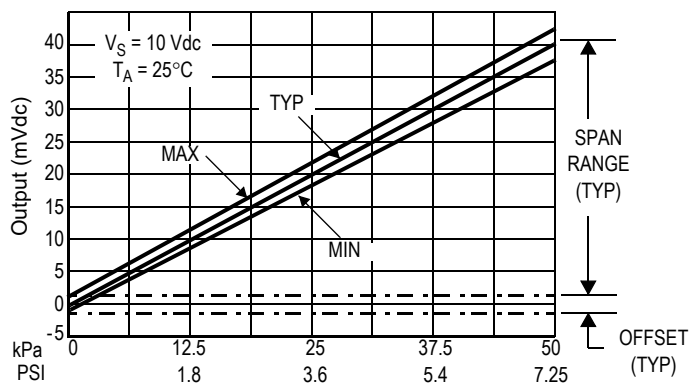
Figure 4. Output versus pressure differential

4   Package Information

4.1   Package dimensions

This drawing is located at http://cache.nxp.com/files/shared/doc/package_info/98ARH99087A.pdf.

Case 98ARH99087A, 5-lead M-PAC

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NOTES:

1. DIMENSIONS ARE IN INCHES.

2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M—1994.

3. DIMENSIONS DOES NOT INCLUDE MOLD FLASH OR PROTRUSION. MOLD FLASH OR
   PROTRUSION SHALL NOT EXCEED .006" PER SIDE.

4. ALL VERTICAL SURFACES TO BE 5" MAXIMUM.

5. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION
   SHALL BE .008 MAXIMUM.

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TITLE: 5 LD M—PAC, PORTED	DOCUMENT NO: 98ARH99087A		REV: B
	STANDARD: NON—JEDEC		
	SOT1673—1		29 FEB 2016

Case 98ARH99087A, 5-lead M-PAC

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5   Revision History

Table 4. Revision history

Revision number	Revision date	Description of changes
4.0	06/2020	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Updated the package image on the first page. • Section 2.2, Table 3, Added new footnote after Linearity, Pressure Hysteresis, Temperature Hysteresis, Temperature Effect on Full Scale Span and Temperature Effect on Offset. • Section 4, Updated the package drawing images.
3.0	11/2015	• Updated format.

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